

## SAM<sup>TM</sup> Data Sheet SAM-1040-10-3ps-x, $\lambda$ = 1040 nm

Laser wavelength  $\lambda = 1040 \text{ nm}$ 

High reflection band  $\lambda = 1000 ... 1110 \text{ nm}$ 

Absorbance  $A_0 = 10 \%$ Modulation depth  $\Delta R = 7 \%$ Non-saturable loss  $A_{ns} = 3 \%$ 

Saturation fluence  $\Phi_{\text{sat}} = 80 \, \mu \text{J/cm}^2$ 

Relaxation time constant  $\tau \sim 3 \text{ ps}$ 

Damage threshold  $\Phi = 3 \text{ mJ/cm}^2$ 

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0unmounted $x = 12.7 \, g$ glued on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$  $x = 25.4 \, g$ glued on a gold plated Cu-cylinder with 25.4 mm  $\varnothing$ 

 $x = 12.7 \, s$ soldered on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$  $x = 25.4 \, s$ soldered on a gold plated Cu-cylinder with 25.4 mm  $\varnothing$ 

x = FC mounted on a 1 m monomode fiber cable with FC connector

## Low intensity spectral reflectance and dispersion

